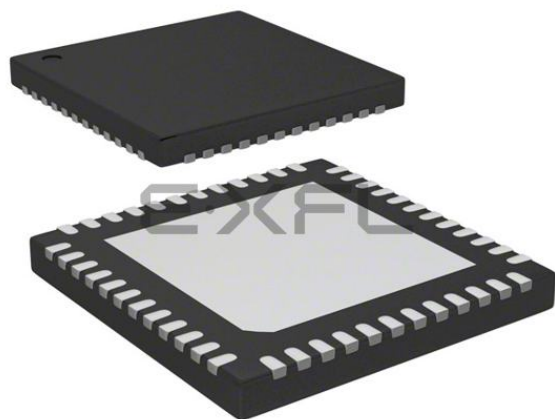




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Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	32MHz
Connectivity	I ² C, SPI, UART/USART, USB
Peripherals	Brown-out Detect/Reset, DMA, LCD, POR, PWM, WDT
Number of I/O	37
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	2K x 8
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 16x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-UFQFN Exposed Pad
Supplier Device Package	-
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32l100c6u6tr

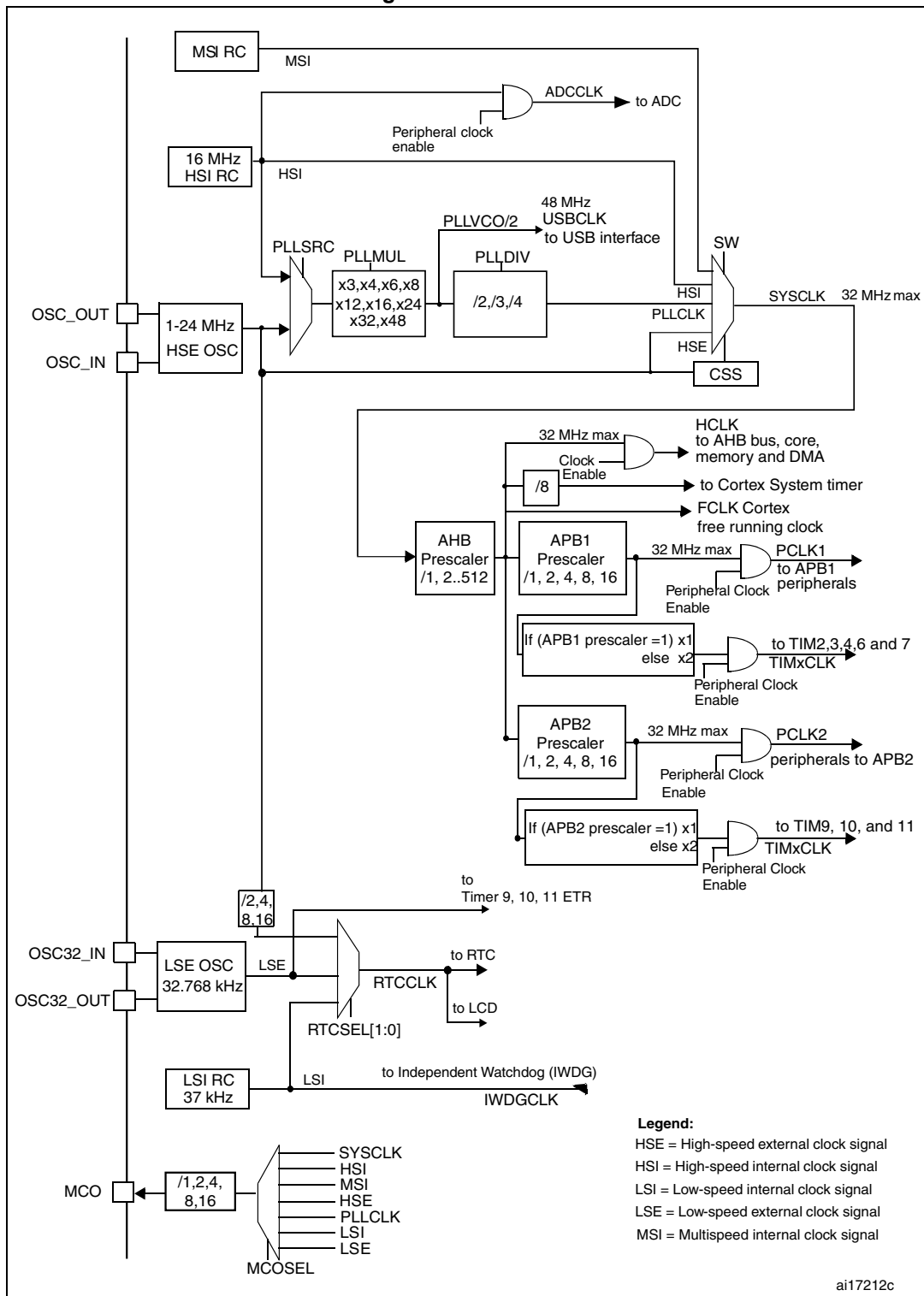
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Figure 2. Clock tree



3.16 CRC (cyclic redundancy check) calculation unit

The CRC (cyclic redundancy check) calculation unit is used to get a CRC code from a 32-bit data word and a fixed generator polynomial.

Among other applications, CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a means of verifying the Flash memory integrity. The CRC calculation unit helps compute a signature of the software during runtime, to be compared with a reference signature generated at link-time and stored at a given memory location.

3.17 Development support

Serial wire JTAG debug port (SWJ-DP)

The ARM SWJ-DP interface is embedded, and is a combined JTAG and serial wire debug port that enables either a serial wire debug or a JTAG probe to be connected to the target. The JTAG JTMS and JTCK pins are shared with SWDAT and SWCLK, respectively, and a specific sequence on the JTMS pin is used to switch between JTAG-DP and SW-DP.

The JTAG port can be permanently disabled with a JTAG fuse.

Table 6. Legend/abbreviations used in the pinout table

Name		Abbreviation	Definition
Pin name		Unless otherwise specified in brackets below the pin name, the pin function during and after reset is the same as the actual pin name	
Pin type	S		Supply pin
	I		Input only pin
	I/O		Input / output pin
I/O structure	FT		5 V tolerant I/O
	TC		Standard 3.3 V I/O
	B		Dedicated BOOT0 pin
	RST		Bidirectional reset pin with embedded weak pull-up resistor
Notes		Unless otherwise specified by a note, all I/Os are set as floating inputs during and after reset	
Pin functions	Alternate functions	Functions selected through GPIOx_AFR registers	
	Additional functions	Functions directly selected/enabled through peripheral registers	

Table 8. Alternate function input/output (continued)

Port name	Digital alternate function number														
	AFIO0	AFIO1	AFIO2	AFIO3	AFIO4	AFIO5	AFIO6	AFIO7	AFIO8	AFIO9	AFIO11	AFIO12	AFIO13	AFIO14	AFIO15
	Alternate function														
	SYSTEM	TIM2	TIM3/4	TIM9/10/11	I2C1/2	SPI1/2	N/A	USART1/2/3	N/A	N/A	LCD	N/A	N/A	RI	SYSTEM
PB4	NJTRST	-	TIM3_CH1	-	-	SPI1_MISO	-	-	-	-	[SEG8]	-	-	-	EVENTOUT
PB5	-	-	TIM3_CH2	-	I2C1_SMBA	SPI1_MOSI	-	-	-	-	[SEG9]	-	-	-	EVENTOUT
PB6	-	-	TIM4_CH1	-	I2C1_SCL	-	-	USART1_TX	-	-	-	-	-	-	EVENTOUT
PB7	-	-	TIM4_CH2	-	I2C1_SDA	-	-	USART1_RX	-	-	-	-	-	-	EVENTOUT
PB8	-	-	TIM4_CH3	TIM10_CH1*	I2C1_SCL	-	-	-	-	-	SEG16	-	-	-	EVENTOUT
PB9	-	-	TIM4_CH4	TIM11_CH1*	I2C1_SDA	-	-	-	-	-	[COM3]	-	-	-	EVENTOUT
PB10	-	TIM2_CH3	-	-	I2C2_SCL	-	-	USART3_TX	-	-	SEG10	-	-	-	EVENTOUT
PB11	-	TIM2_CH4	-	-	I2C2_SDA	-	-	USART3_RX	-	-	SEG11	-	-	-	EVENTOUT
PB12	-	-	-	TIM10_CH1	I2C2_SMBA	SPI2_NSS	-	USART3_CK	-	-	SEG12	-	-	-	EVENTOUT
PB13	-	-	-	TIM9_CH1	-	SPI2_SCK	-	USART3_CTS	-	-	SEG13	-	-	-	EVENTOUT
PB14	-	-	-	TIM9_CH2	-	SPI2_MISO	-	USART3_RTS	-	-	SEG14	-	-	-	EVENTOUT
PB15	-	-	-	TIM11_CH1	-	SPI2_MOSI	-	-	-	-	SEG15	-	-	-	EVENTOUT
PC0	-	-	-	-	-	-	-	-	-	-	SEG18	-	-	TIMx_IC1	EVENTOUT
PC1	-	-	-	-	-	-	-	-	-	-	SEG19	-	-	TIMx_IC2	EVENTOUT
PC2	-	-	-	-	-	-	-	-	-	-	SEG20	-	-	TIMx_IC3	EVENTOUT
PC3	-	-	-	-	-	-	-	-	-	-	SEG21	-	-	TIMx_IC4	EVENTOUT
PC4	-	-	-	-	-	-	-	-	-	-	SEG22	-	-	TIMx_IC1	EVENTOUT
PC5	-	-	-	-	-	-	-	-	-	-	SEG23	-	-	TIMx_IC2	EVENTOUT
PC6	-	-	TIM3_CH1	-	-	-	-	-	-	-	SEG24	-	-	TIMx_IC3	EVENTOUT
PC7	-	-	TIM3_CH2	-	-	-	-	-	-	-	SEG25	-	-	TIMx_IC4	EVENTOUT
PC8	-	-	TIM3_CH3	-	-	-	-	-	-	-	SEG26	-	-	TIMx_IC1	EVENTOUT
PC9	-	-	TIM3_CH4	-	-	-	-	-	-	-	SEG27	-	-	TIMx_IC2	EVENTOUT



Table 8. Alternate function input/output (continued)

Port name	Digital alternate function number														
	AFIO0	AFIO1	AFIO2	AFIO3	AFIO4	AFIO5	AFIO6	AFIO7	AFIO8	AFIO9	AFIO11	AFIO12	AFIO13	AFIO14	AFIO15
	Alternate function														
	SYSTEM	TIM2	TIM3/4	TIM9/10/11	I2C1/2	SPI1/2	N/A	USART1/2/3	N/A	N/A	LCD	N/A	N/A	RI	SYSTEM
PC10	-	-	-	-	-	-	-	USART3_TX	-	-	COM4 / SEG28 / SEG40	-	-	TIMx_IC3	EVENTOUT
PC11	-	-	-	-	-	-	-	USART3_RX	-	-	COM5 / SEG29 / SEG41	-	-	TIMx_IC4	EVENTOUT
PC12	-	-	-	-	-	-	-	USART3_CK	-	-	COM6 / SEG30 / SEG42	-	-	TIMx_IC1	EVENTOUT
PC13-WKUP2	-	-	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC2	EVENTOUT
PC14-OSC32_IN	-	-	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC3	EVENTOUT
PC15-OSC32_OUT	-	-	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC4	EVENTOUT
PD2	-	-	TIM3_ETR	-	-	-	-	-	-	-	COM7 / SEG31 / SEG43	-	-	TIMx_IC3	EVENTOUT
PH0-OSC_IN	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-
PH1-OSC_OUT	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-

6.3.3 Embedded internal reference voltage

The parameters given in the following table are based on characterization results, unless otherwise specified.

Table 14. Embedded internal reference voltage calibration values

Calibration value name	Description	Memory address
VREFINT_CAL	Raw data acquired at temperature of 30 °C $\pm$ 5 °C, $V_{DDA} = 3 \text{ V} \pm 10 \text{ mV}$	0x1FF8 0078-0x1FF8 0079

Table 15. Embedded internal reference voltage

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{\text{REFINT_out}}^{(1)}$	Internal reference voltage	$-40\text{ °C} < T_J < +85\text{ °C}$	1.202	1.224	1.242	V
I_{REFINT}	Internal reference current consumption	-	-	1.4	2.3	μA
T_{VREFINT}	Internal reference startup time	-	-	2	3	ms
$V_{\text{VREF_MEAS}}$	V_{DDA} voltage during V_{REFINT} factory measure	-	2.99	3	3.01	V
$A_{\text{VREF_MEAS}}$	Accuracy of factory-measured V_{REF} value ⁽²⁾	Including uncertainties due to ADC and V_{DDA} values	-	-	± 5	mV
$T_{\text{Ccoeff}}^{(3)}$	Temperature coefficient	$-40\text{ °C} < T_J < +105\text{ °C}$	-	25	100	ppm/°C
$A_{\text{Ccoeff}}^{(3)}$	Long-term stability	1000 hours, $T = 25\text{ °C}$	-	-	1000	ppm
$V_{\text{DDCcoeff}}^{(3)(4)}$	Voltage coefficient	$3.0\text{ V} < V_{\text{DDA}} < 3.6\text{ V}$	-	-	2000	ppm/V
$T_{\text{S_vrefint}}^{(3)}$	ADC sampling time when reading the internal reference voltage	-	4	-	-	μs
$T_{\text{ADC_BUF}}^{(3)}$	Startup time of reference voltage buffer for ADC	-	-	-	10	μs
$I_{\text{BUF_ADC}}^{(3)}$	Consumption of reference voltage buffer for ADC	-	-	13.5	25	μA
$I_{\text{VREF_OUT}}^{(3)}$	VREF_OUT output current ⁽⁵⁾	-	-	-	1	μA
$C_{\text{VREF_OUT}}^{(3)}$	VREF_OUT output load	-	-	-	50	pF
$I_{\text{LPBUF}}^{(3)}$	Consumption of reference voltage buffer for VREF_OUT and COMP	-	-	730	1200	nA
$V_{\text{REFINT_DIV1}}^{(3)}$	1/4 reference voltage	-	24	25	26	% V_{REFINT}
$V_{\text{REFINT_DIV2}}^{(3)}$	1/2 reference voltage	-	49	50	51	
$V_{\text{REFINT_DIV3}}^{(3)}$	3/4 reference voltage	-	74	75	76	

1. Guaranteed by test in production.

2. The internal V_{REF} value is individually measured in production and stored in dedicated EEPROM bytes.

3. Guaranteed by characterization results.

4. Shortest sampling time can be determined in the application by multiple interactions.

5. To guarantee less than 1% VREF_OUT deviation.

Table 16. Current consumption in Run mode, code with data processing running from Flash

Symbol	Parameter	Conditions		f _{HCLK}	Typ	Max ⁽¹⁾		Unit
						55 °C	85 °C	
I _{DD} (Run from Flash)	Supply current in Run mode, code executed from Flash	f _{HSE} = f _{HCLK} up to 16 MHz, included f _{HSE} = f _{HCLK} /2 above 16 MHz (PLL ON) ⁽²⁾	Range 3, V _{CORE} =1.2 V VOS[1:0] = 11	1 MHz	270	400	400	μA
				2 MHz	470	600	600	
				4 MHz	890	1025	1025	
			Range 2, V _{CORE} =1.5 V VOS[1:0] = 10	4 MHz	1	1.3	1.3	mA
				8 MHz	2	2.5	2.5	
				16 MHz	3.9	5	5	
			Range 1, V _{CORE} =1.8 V VOS[1:0] = 01	8 MHz	2.16	3	3	
				16 MHz	4.8	5.5	5.5	
				32 MHz	9.6	11	11	
		HSI clock source (16 MHz)	Range 2, V _{CORE} =1.5 V VOS[1:0] = 10	16 MHz	4	5	5	
			Range 1, V _{CORE} =1.8 V VOS[1:0] = 01	32 MHz	9.4	11	11	
		MSI clock, 65 kHz	Range 3, V _{CORE} =1.2 V VOS[1:0] = 11	65 kHz	0.05	0.085	0.09	
		MSI clock, 524 kHz		524 kHz	0.15	0.185	0.19	
		MSI clock, 4.2 MHz		4.2 MHz	0.9	1	1	

1. Guaranteed by characterization results, unless otherwise specified.

2. Oscillator bypassed (HSEBYP = 1 in RCC_CR register).

Table 17. Current consumption in Run mode, code with data processing running from RAM

Symbol	Parameter	Conditions		f _{HCLK}	Typ	Max ⁽¹⁾	Unit
						105 °C	
I _{DD} (Run from RAM)	Supply current in Run mode, code executed from RAM, Flash switched off	f _{HSE} = f _{HCLK} up to 16 MHz, included f _{HSE} = f _{HCLK} /2 above 16 MHz (PLL ON) ⁽²⁾	Range 3, V _{CORE} =1.2 V VOS[1:0] = 11	1 MHz	200	300	μA
				2 MHz	380	500	
				4 MHz	720	860	
			Range 2, V _{CORE} =1.5 V VOS[1:0] = 10	4 MHz	0.9	1	mA
				8 MHz	1.65	2	
				16 MHz	3.2	3.7	
			Range 1, V _{CORE} =1.8 V VOS[1:0] = 01	8 MHz	2	2.5	
				16 MHz	4	4.5	
				32 MHz	7.7	8.5	
		HSI clock source (16 MHz)	Range 2, V _{CORE} =1.5 V VOS[1:0] = 10	16 MHz	3.3	3.8	
			Range 1, V _{CORE} =1.8 V VOS[1:0] = 01	32 MHz	7.8	9.2	
		MSI clock, 65 kHz	Range 3, V _{CORE} =1.2 V VOS[1:0] = 11	65 kHz	40	80	μA
		MSI clock, 524 kHz		524 kHz	110	160	
		MSI clock, 4.2 MHz		4.2 MHz	700	820	

1. Guaranteed by characterization results, unless otherwise specified.

2. Oscillator bypassed (HSEBYP = 1 in RCC_CR register).

Table 19. Current consumption in Low power run mode

Symbol	Parameter	Conditions			Typ	Max (1)	Unit	
I _{DD} (LP Run)	Supply current in Low power run mode	All peripherals OFF, code executed from RAM, Flash switched OFF, V _{DD} from 1.8 V to 3.6 V	MSI clock, 65 kHz f _{HCLK} = 32 kHz	T _A = -40 °C to 25 °C	9	12	μA	
				T _A = 85 °C	17.5	24		
			MSI clock, 65 kHz f _{HCLK} = 65 kHz	T _A = -40 °C to 25 °C	14	17		
				T _A = 85 °C	22	29		
			MSI clock, 131 kHz f _{HCLK} = 131 kHz	T _A = -40 °C to 25 °C	37	42		
				T _A = 55 °C	37	42		
				T _A = 85 °C	37	42		
			All peripherals OFF, code executed from Flash, V _{DD} from 1.8 V to 3.6 V	MSI clock, 65 kHz f _{HCLK} = 32 kHz	T _A = -40 °C to 25 °C	24		32
					T _A = 85 °C	33		42
		MSI clock, 65 kHz f _{HCLK} = 65 kHz		T _A = -40 °C to 25 °C	31	40		
				T _A = 85 °C	40	48		
		MSI clock, 131 kHz f _{HCLK} = 131 kHz		T _A = -40 °C to 25 °C	48	58		
				T _A = 55 °C	54	63		
			T _A = 85 °C	56	65			
		I _{DD} Max (LP Run) ⁽²⁾	Max allowed current in Low power run mode	V _{DD} from 1.8 V to 3.6 V	-	-		-

1. Guaranteed by characterization results, unless otherwise specified.

2. This limitation is related to the consumption of the CPU core and the peripherals that are powered by the regulator. Consumption of the I/Os is not included in this limitation.

Table 20. Current consumption in Low power sleep mode

Symbol	Parameter	Conditions			Typ	Max (1)	Unit
I_{DD} (LP Sleep)	Supply current in Low power sleep mode	All peripherals OFF, V_{DD} from 1.8 V to 3.6 V	MSI clock, 65 kHz $f_{HCLK} = 32$ kHz Flash OFF	$T_A = -40\text{ }^{\circ}\text{C}$ to $25\text{ }^{\circ}\text{C}$	4.4	-	μA
			MSI clock, 65 kHz $f_{HCLK} = 32$ kHz Flash ON	$T_A = -40\text{ }^{\circ}\text{C}$ to $25\text{ }^{\circ}\text{C}$	17.5	25	
				$T_A = 85\text{ }^{\circ}\text{C}$	22	27	
			MSI clock, 65 kHz $f_{HCLK} = 65$ kHz, Flash ON	$T_A = -40\text{ }^{\circ}\text{C}$ to $25\text{ }^{\circ}\text{C}$	18	26	
				$T_A = 85\text{ }^{\circ}\text{C}$	23	28	
			MSI clock, 131 kHz $f_{HCLK} = 131$ kHz, Flash ON	$T_A = -40\text{ }^{\circ}\text{C}$ to $25\text{ }^{\circ}\text{C}$	22	30	
				$T_A = 55\text{ }^{\circ}\text{C}$	24	32	
				$T_A = 85\text{ }^{\circ}\text{C}$	26	34	
		TIM9 and USART1 enabled, Flash ON, V_{DD} from 1.8 V to 3.6 V	MSI clock, 65 kHz $f_{HCLK} = 32$ kHz	$T_A = -40\text{ }^{\circ}\text{C}$ to $25\text{ }^{\circ}\text{C}$	17.5	25	
				$T_A = 85\text{ }^{\circ}\text{C}$	22	27	
			MSI clock, 65 kHz $f_{HCLK} = 65$ kHz	$T_A = -40\text{ }^{\circ}\text{C}$ to $25\text{ }^{\circ}\text{C}$	18	26	
				$T_A = 85\text{ }^{\circ}\text{C}$	23	28	
			MSI clock, 131 kHz $f_{HCLK} = 131$ kHz	$T_A = -40\text{ }^{\circ}\text{C}$ to $25\text{ }^{\circ}\text{C}$	22	30	
				$T_A = 55\text{ }^{\circ}\text{C}$	24	32	
				$T_A = 85\text{ }^{\circ}\text{C}$	26	34	
I_{DD} Max (LP Sleep)	Max allowed current in Low power Sleep mode	V_{DD} from 1.8 V to 3.6 V	-	-	-	200	

1. Guaranteed by characterization results, unless otherwise specified.

Table 23. Peripheral current consumption⁽¹⁾ (continued)

Peripheral		Typical consumption, V _{DD} = 3.0 V, T _A = 25 °C				Unit
		Range 1, V _{CORE} =1.8 V VOS[1:0] = 01	Range 2, V _{CORE} =1.5 V VOS[1:0] = 10	Range 3, V _{CORE} =1.2 V VOS[1:0] = 11	Low power sleep and run	
AHB	GPIOA	5	4.5	3.5	4	μA/MHz (f _{HCLK})
	GPIOB	5	4.5	3.5	4.5	
	GPIOC	5	4.5	3.5	4.5	
	GPIOD	5	4.5	3.5	4.5	
	GPIOH	4	4	3	3.5	
	CRC	1	0.5	0.5	0.5	
	FLASH	13	11.5	9	18.5	
	DMA1	12	10	8	10.5	
All enabled		166	138	106	130	
I _{DD} (RTC)		0.47				μA
I _{DD} (LCD)		3.1				
I _{DD} (ADC) ⁽³⁾		1450				
I _{DD} (DAC) ⁽⁴⁾		340				
I _{DD} (COMP1)		0.16				
I _{DD} (COMP2)	Slow mode	2				
	Fast mode	5				
I _{DD} (PVD / BOR) ⁽⁵⁾		2.6				
I _{DD} (IWDG)		0.25				

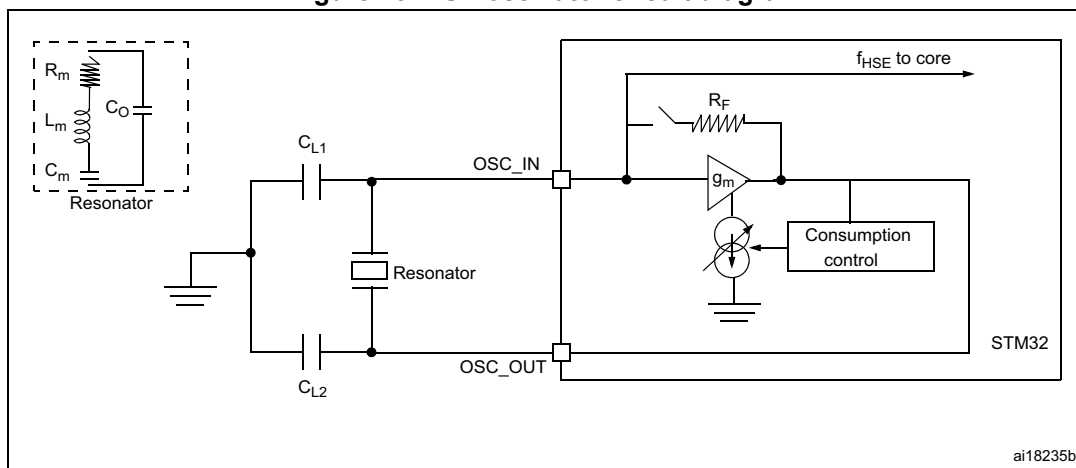
1. Data based on differential I_{DD} measurement between all peripherals OFF and one peripheral with clock enabled, in the following conditions: f_{HCLK} = 32 MHz (Range 1), f_{HCLK} = 16 MHz (Range 2), f_{HCLK} = 4 MHz (Range 3), f_{HCLK} = 64kHz (Low power run/sleep), f_{APB1} = f_{HCLK}, f_{APB2} = f_{HCLK}, default prescaler value for each peripheral. The CPU is in Sleep mode in both cases. No I/O pins toggling.
2. HSI oscillator is OFF for this measure.
3. Data based on a differential I_{DD} measurement between ADC in reset configuration and continuous ADC conversion (HSI consumption not included).
4. Data based on a differential I_{DD} measurement between DAC in reset configuration and continuous DAC conversion of V_{DD}/2. DAC is in buffered mode, output is left floating.
5. Including supply current of internal reference voltage.

6.3.5 Wakeup time from Low-power mode

The wakeup times given in the following table are measured with the MSI RC oscillator. The clock source used to wake up the device depends on the current operating mode:

- Sleep mode: the clock source is the clock that was set before entering Sleep mode
- Stop mode: the clock source is the MSI oscillator in the range configured before entering Stop mode
- Standby mode: the clock source is the MSI oscillator running at 2.1 MHz

Figure 13. HSE oscillator circuit diagram



1. R_{EXT} value depends on the crystal characteristics.

Low-speed external clock generated from a crystal/ceramic resonator

The low-speed external (LSE) clock can be supplied with a 32.768 kHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on characterization results obtained with typical external components specified in [Table 12](#). In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

Table 28. LSE oscillator characteristics ($f_{LSE} = 32.768 \text{ kHz}$)⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{LSE}	Low speed external oscillator frequency	-	-	32.768	-	kHz
R_F	Feedback resistor	-	-	1.2	-	MΩ
$C^{(2)}$	Recommended load capacitance versus equivalent serial resistance of the crystal (R_S) ⁽³⁾	$R_S = 30 \text{ k}\Omega$	-	8	-	pF
I_{LSE}	LSE driving current	$V_{DD} = 3.3 \text{ V}$, $V_{IN} = V_{SS}$	-	-	1.1	μA
$I_{DD} \text{ (LSE)}$	LSE oscillator current consumption	$V_{DD} = 1.8 \text{ V}$	-	450	-	nA
		$V_{DD} = 3.0 \text{ V}$	-	600	-	
		$V_{DD} = 3.6 \text{ V}$	-	750	-	
g_m	Oscillator transconductance	-	3	-	-	μA/V
$t_{SU(LSE)}^{(4)}$	Startup time	V_{DD} is stabilized	-	1	-	s

1. Guaranteed by characterization results.
2. Refer to the note and caution paragraphs below the table, and to the application note AN2867 "Oscillator design guide for ST microcontrollers".
3. The oscillator selection can be optimized in terms of supply current using an high quality resonator with small R_S value for example MSIV-TIN32.768kHz. Refer to crystal manufacturer for more details.
4. $t_{SU(LSE)}$ is the startup time measured from the moment it is enabled (by software) to a stabilized 32.768 kHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer.

6.3.16 Communication interfaces

I²C interface characteristics

The STM32L100C6 and STM32L100R8/RB product line I²C interface meets the requirements of the standard I²C communication protocol with the following restrictions: SDA and SCL are not “true” open-drain I/O pins. When configured as open-drain, the PMOS connected between the I/O pin and V_{DD} is disabled, but is still present.

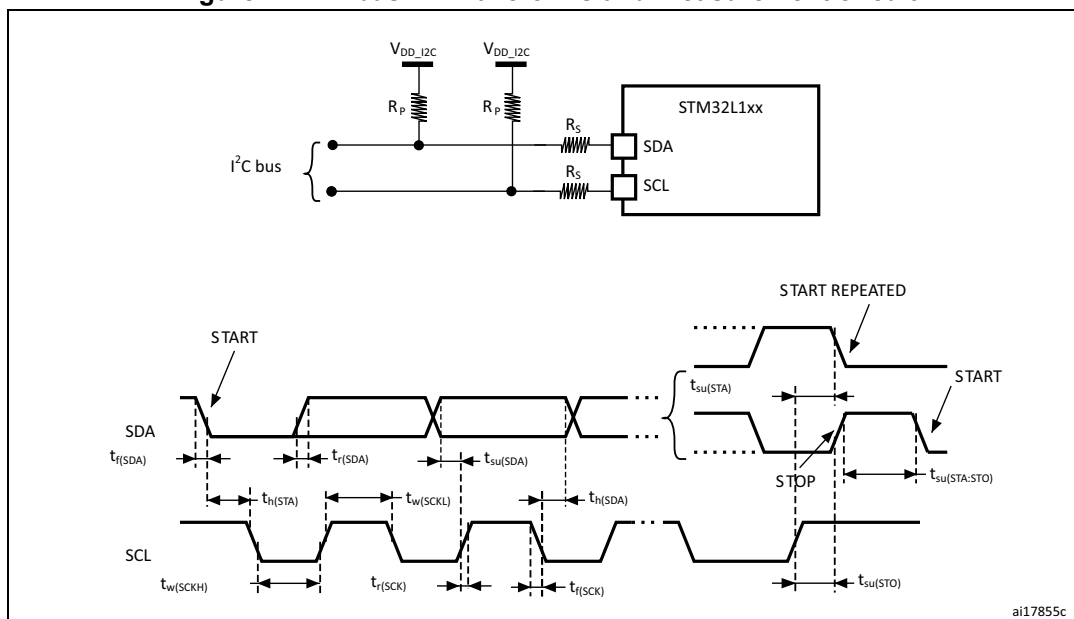
The I²C characteristics are described in [Table 46](#). Refer also to [Section 6.3.12: I/O current injection characteristics](#) for more details on the input/output alternate function characteristics (SDA and SCL).

Table 46. I²C characteristics

Symbol	Parameter	Standard mode I ² C ⁽¹⁾⁽²⁾		Fast mode I ² C ⁽¹⁾⁽²⁾		Unit
		Min	Max	Min	Max	
t _w (SCLL)	SCL clock low time	4.7	-	1.3	-	μs
t _w (SCLH)	SCL clock high time	4.0	-	0.6	-	
t _{su} (SDA)	SDA setup time	250	-	100	-	ns
t _h (SDA)	SDA data hold time	-	3450 ⁽³⁾	-	900 ⁽³⁾	
t _r (SDA) t _r (SCL)	SDA and SCL rise time	-	1000	-	300	
t _f (SDA) t _f (SCL)	SDA and SCL fall time	-	300	-	300	
t _h (STA)	Start condition hold time	4.0	-	0.6	-	μs
t _{su} (STA)	Repeated Start condition setup time	4.7	-	0.6	-	
t _{su} (STO)	Stop condition setup time	4.0	-	0.6	-	μs
t _w (STO:STA)	Stop to Start condition time (bus free)	4.7	-	1.3	-	μs
C _b	Capacitive load for each bus line	-	400	-	400	pF
t _{SP}	Pulse width of spikes that are suppressed by the analog filter	0	50 ⁽⁴⁾	0	50 ⁽⁴⁾	ns

1. Guaranteed by design.
2. f_{PCLK1} must be at least 2 MHz to achieve standard mode I²C frequencies. It must be at least 4 MHz to achieve fast mode I²C frequencies. It must be a multiple of 10 MHz to reach the 400 kHz maximum I²C fast mode clock.
3. The maximum Data hold time has only to be met if the interface does not stretch the low period of SCL signal.
4. The minimum width of the spikes filtered by the analog filter is above t_{SP(max)}.

Figure 17. I²C bus AC waveforms and measurement circuit



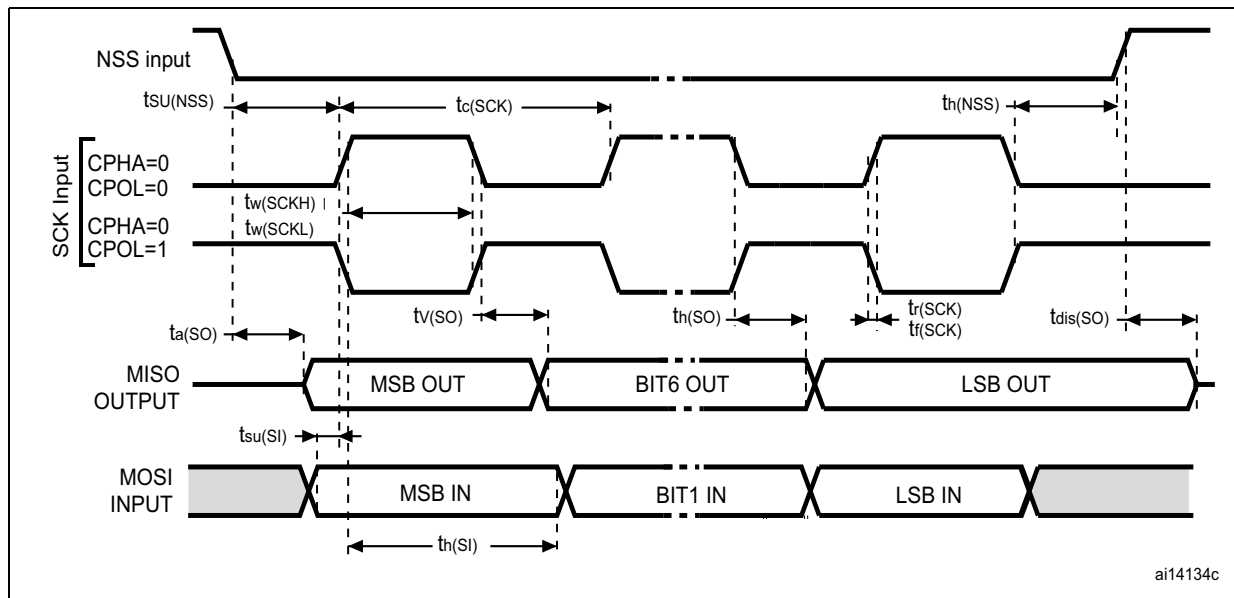
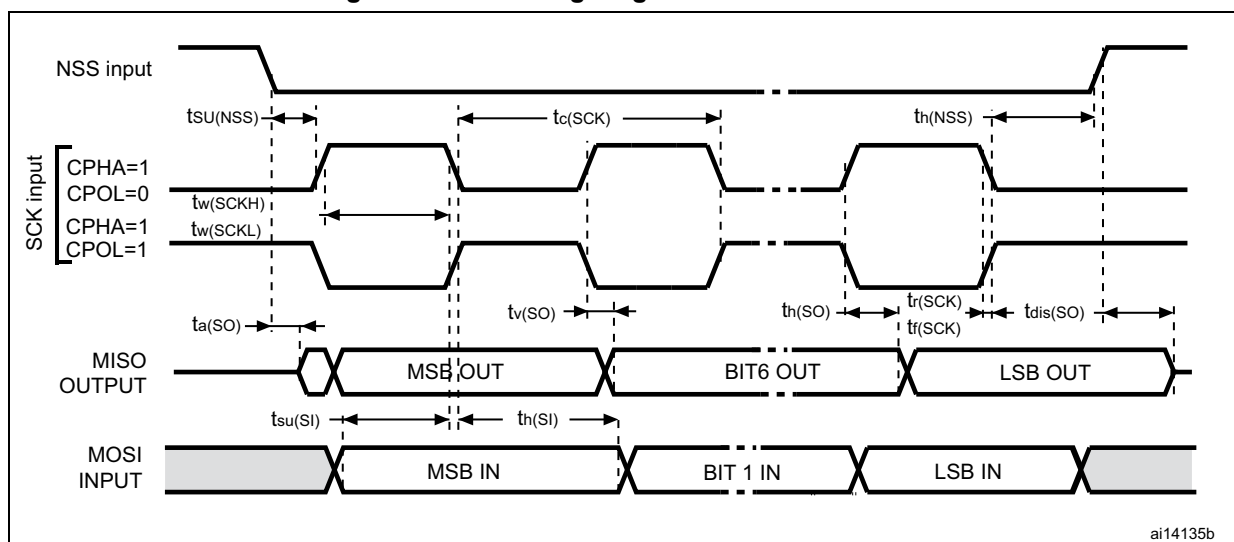
1. R_S = series protection resistors
2. R_P = pull-up resistors
3. V_{DD_I2C} = I2C bus supply
4. Measurement points are done at CMOS levels: $0.3V_{DD}$ and $0.7V_{DD}$.

Table 47. SCL frequency ($f_{\text{PCLK1}} = 32 \text{ MHz}$, $V_{\text{DD}} = V_{\text{DD I2C}} = 3.3 \text{ V}$)⁽¹⁾⁽²⁾

f _{SCL} (kHz)	I2C_CCR value
	R _p = 4.7 kΩ
400	0x801B
300	0x8024
200	0x8035
100	0x00A0
50	0x0140
20	0x0320

1. R_p = External pull-up resistance, f_{SCL} = I^2C speed.
2. For speeds around 200 kHz, the tolerance on the achieved speed is of $\pm 5\%$. For other speed ranges, the tolerance on the achieved speed is $\pm 2\%$. These variations depend on the accuracy of the external components used to design the application.

Figure 18. SPI timing diagram - slave mode and CPHA = 0

Figure 19. SPI timing diagram - slave mode and CPHA = 1⁽¹⁾

1. Measurement points are done at CMOS levels: $0.3V_{DD}$ and $0.7V_{DD}$.

6.3.20 LCD controller

The STM32L100C6 and STM32L100R8/RB devices embed a built-in step-up converter to provide a constant LCD reference voltage independently from the V_{DD} voltage. An external capacitor C_{ext} must be connected to the V_{LCD} pin to decouple this converter.

Table 59. LCD controller characteristics

Symbol	Parameter	Min	Typ	Max	Unit
V_{LCD}	LCD external voltage	-	-	3.6	V
V_{LCD0}	LCD internal reference voltage 0	-	2.6	-	
V_{LCD1}	LCD internal reference voltage 1	-	2.73	-	
V_{LCD2}	LCD internal reference voltage 2	-	2.86	-	
V_{LCD3}	LCD internal reference voltage 3	-	2.98	-	
V_{LCD4}	LCD internal reference voltage 4	-	3.12	-	
V_{LCD5}	LCD internal reference voltage 5	-	3.26	-	
V_{LCD6}	LCD internal reference voltage 6	-	3.4	-	
V_{LCD7}	LCD internal reference voltage 7	-	3.55	-	
C_{ext}	V_{LCD} external capacitance	0.1	-	2	μF
$I_{LCD}^{(1)}$	Supply current at $V_{DD} = 2.2 V$	-	3.3	-	μA
	Supply current at $V_{DD} = 3.0 V$	-	3.1	-	
$R_{Htot}^{(2)}$	Low drive resistive network overall value	5.28	6.6	7.92	$M\Omega$
$R_L^{(2)}$	High drive resistive network total value	192	240	288	$k\Omega$
V_{44}	Segment/Common highest level voltage	-	-	V_{LCD}	V
V_{34}	Segment/Common 3/4 level voltage	-	$3/4 V_{LCD}$	-	V
V_{23}	Segment/Common 2/3 level voltage	-	$2/3 V_{LCD}$	-	
V_{12}	Segment/Common 1/2 level voltage	-	$1/2 V_{LCD}$	-	
V_{13}	Segment/Common 1/3 level voltage	-	$1/3 V_{LCD}$	-	
V_{14}	Segment/Common 1/4 level voltage	-	$1/4 V_{LCD}$	-	
V_0	Segment/Common lowest level voltage	0	-	-	
$\Delta V_{xx}^{(2)}$	Segment/Common level voltage error $T_A = -40$ to $85^\circ C$	-	-	± 50	mV

1. LCD enabled with 3 V internal step-up active, 1/8 duty, 1/4 bias, division ratio= 64, all pixels active, no LCD connected

2. Guaranteed by characterization results.

Table 64. Document revision history (continued)

Date	Revision	Changes
31-Mar-2014 (continued)	2	Deleted second footnote in Figure 30. Updated Section 6.3.11: Electrical sensitivity characteristics title. Updated section link in second paragraph of Section 6.3.15: TIM timer characteristics. Removed all occurrences of “when 8 pins are sourced at same time” in Table 42: Output voltage characteristics. Modified first sentence in Section 6.3.14: NRST pin characteristics. Updated text and removed figure Power supply and reference decoupling in General PCB design guidelines. Updated sub-section TIM10, TIM11 and TIM9. In Table 58: Comparator 2 characteristics, parameter dThreshold/dt, replaced all occurrences of “V_{REF+}” with “V_{REFINT}”. Updated: – Table 4: Working mode-dependent functionalities (from Run/active down to standby) – Table 5: Timer feature comparison – Table 7: STM32L100C6 and STM32L100R8/RB pin definitions – Table 9: Voltage characteristics – Table 12: General operating conditions – Table 15: Embedded internal reference voltage – Table 25: High-speed external user clock characteristics – Table 28: LSE oscillator characteristics (fLSE = 32.768 kHz) – Table 29: HSI oscillator characteristics – Table 38: ESD absolute maximum ratings – Table 40: I/O current injection susceptibility – Table 41: I/O static characteristics – Table 42: Output voltage characteristics – Table 44: NRST pin characteristics – Table 61: UFQFPN48 7 x 7 mm, 0.5 mm pitch, package mechanical data – Table 62: Thermal characteristics, Table 53: ADC characteristics Updated: – Figure 6: Pin loading conditions – Figure 7: Pin input voltage – Figure 8: Power supply scheme – Figure 10: Current consumption measurement scheme – Figure 17: I2C bus AC waveforms and measurement circuit – Figure 23: Typical connection diagram using the ADC – Figure 32: Thermal resistance Added: – Figure 28: LQFP64 10 x 10 mm, 64-pin low-profile quad flat package top view example – Figure 31: UFQFPN48 7 x 7 mm, 0.5 mm pitch, package top view example – Table 6: Legend/abbreviations used in the pinout table
10-Apr-2014	3	Updated 10 KB RAM in Cover & description.